SDP8436

Silicon Phototransistor

FEATURES

- Side-looking plastic package
- 18° (nominal) acceptance angle
- Enhanced coupling distance
- Internal visible light rejection filter
- Low profile for design flexibility
- · Wide sensitivity ranges

DESCRIPTION

 Mechanically matched to SEP8736 infrared emitting diode

The SDP8436 is an NPN silicon phototransistor molded

in a black plastic package which combines the mounting

advantages of a side-looking package with the narrow acceptance angle and high optical gain of a T- 1 package. The SDP8436 is designed for those

applications which require longer coupling distances

than standard side-looking devices can provide, such as touch screens. The device is also well suited to

applications in which adjacent channel crosstalk could

IR source energy while it provides effective shielding

against visible ambient light.

be a problem. The package is highly transmissive to the

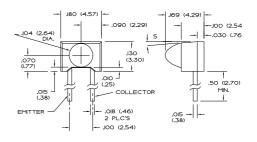


INFRA-82.TIF

OUTLINE DIMENSIONS in inches (mm)

Tolerance

3 plc decimals ±0.005(0.12) 2 plc decimals ±0.020(0.51)



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ELECTRICAL CHARACTERISTICS	(25°C unless otherwise noted)
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PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Light Current	۱ <u>ـ</u>				mA	V _{CE} =5 V
SDP8436-001		0.50				H=1 mW/cm ^{2 (1)}
SDP8436-002		4.00		10.0		
SDP8436-003		7.00		17.5		
SDP8436-004		12.5				
Collector Dark Current	ICEO			100	nA	V _{CE} =15 V, H=0
Collector-Emitter Breakdown Voltage	V(BR)CEO	30			V	Ic=100 μΑ
Emitter-Collector Breakdown Voltage	V(BR)ECO	5.0			V	I _E =100 μA
Collector-Emitter Saturation Voltage	VCE(SAT)			0.4	V	Ic=0.1 mA
						H=1 mW/cm ²
Angular Response (2)	Ø		18		degr.	I⊧=Constant
Rise And Fall Time	tr, tf		15		μs	Vcc=5 V, I∟=1 mA
						RL=1000 Ω

Notes 1. The radiation source is an IRED with a peak wavelength of 880 nm. 2. Angular response is defined as the total included angle between the half sensitivity points.

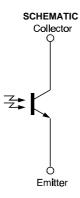
ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5 V
Power Dissipation	100 mW (1)
Operating Temperature Range	-40°C to 85°C
Storage Temperature Range	-40°C to 85°C
Soldering Temperature (5 sec)	240°C

Notes

1. Derate linearly from 25°C free-air temperature at the rate of 0.78 mW/°C.

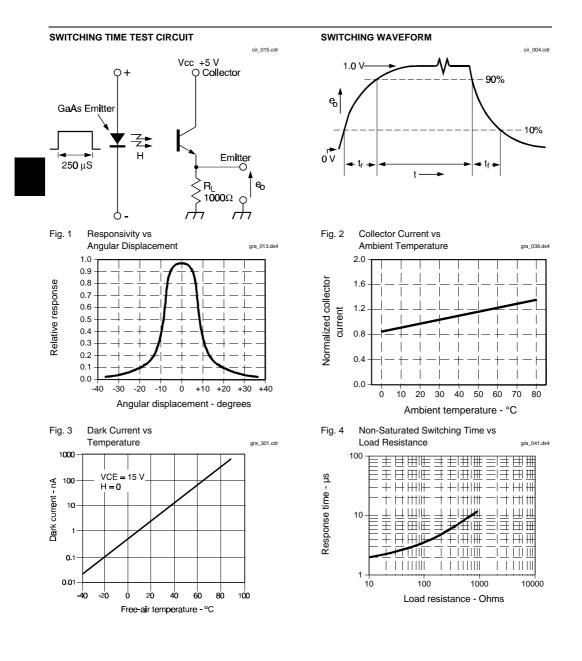


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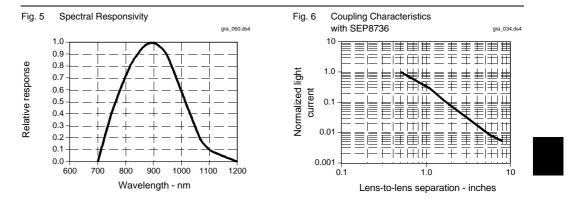


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All Performance Curves Show Typical Values

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